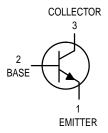
# **One Watt Amplifier Transistors**

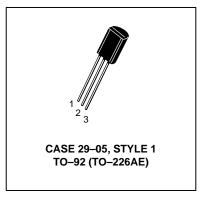
**NPN Silicon** 



#### **MAXIMUM RATINGS**

Rating	Symbol Value		Unit	
Collector-Emitter Voltage MPS6714 MPS6715	VCEO	30 40	Vdc	
Collector-Base Voltage MPS6714 MPS6715	VCBO	40 50	Vdc	
Emitter-Base Voltage	VEBO	5.0	Vdc	
Collector Current — Continuous	IC	1.0	Adc	
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	1.0 8.0	Watts mW/°C	
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	2.5 20	Watts mW/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C	

## MPS6714 MPS6715



#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	125	°C/W
Thermal Resistance, Junction to Case	$R_{ heta}$ JC	50	°C/W

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage <sup>(1)</sup> (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 0)	MPS6714 MPS6715	V(BR)CEO	30 40		Vdc
Collector–Base Breakdown Voltage (I <sub>C</sub> = 100 μAdc, I <sub>E</sub> = 0)	MPS6714 MPS6715	V(BR)CBO	40 50	_ _	Vdc
Emitter-Base Breakdown Voltage (I <sub>E</sub> = 100 μAdc, I <sub>C</sub> = 0)		V(BR)EBO	5.0	_	Vdc
Collector Cutoff Current (VCB = 40 Vdc, IE = 0) (VCB = 50 Vdc, IE = 0)	MPS6714 MPS6715	ICBO	_ _	0.1 0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 5.0 Vdc, I <sub>C</sub> = 0)		IEBO	_	0.1	μAdc

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  30  $\mu s;$  Duty Cycle  $\leq$  2.0%.



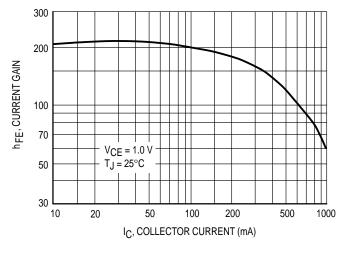
#### MPS6714 MPS6715

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS(1)	•			•
DC Current Gain (I <sub>C</sub> = 100 mAdc, V <sub>CE</sub> = 1.0 Vdc) (I <sub>C</sub> = 1000 mAdc, V <sub>CE</sub> = 1.0 Vdc)	hFE	60 50	_ 250	_
Collector-Emitter Saturation Voltage (IC = 1000 mAdc, IB = 100 mAdc)	VCE(sat)	_	0.5	Vdc
Base-Emitter On Voltage (I <sub>C</sub> = 1000 mAdc, V <sub>CE</sub> = 1.0 Vdc)	V <sub>BE</sub> (on)	_	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS	·	•	•	
Collector–Base Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)		_	30	pF
Small–Signal Current Gain (I <sub>C</sub> = 50 mAdc, V <sub>CE</sub> = 10 Vdc, f = 20 MHz)	h <sub>fe</sub>	2.5	25	_

1.0

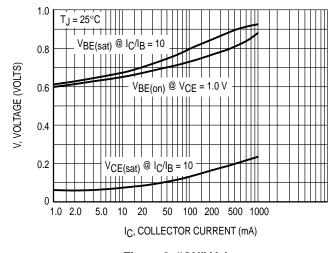
<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  30  $\mu$ s; Duty Cycle  $\leq$  2.0%.



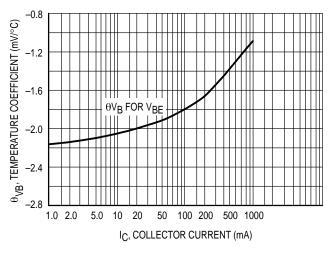
V<sub>CE</sub>, COLLECTOR VOLTAGE (VOLTS) 0.8 0.6 IC = 000 mA 0.4 IC = 500 mA IC = IC = IC = 250 mA 0.2 10 mA 50 mA 100 mA 5.0 0.01 0.02 0.05 0.1 0.2 0.5 1.0 2.0 20 50 100 IB, BASE CURRENT (mA)

Figure 1. DC Current Gain

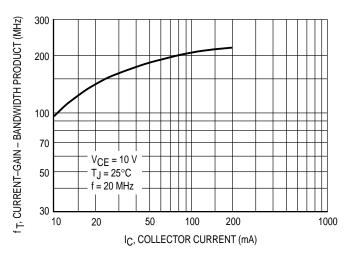
Figure 2. Collector Saturation Region







**Figure 4. Temperature Coefficient** 



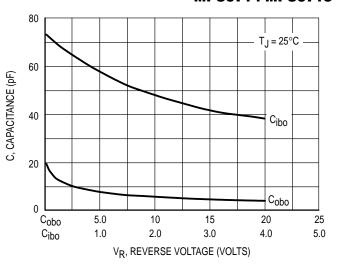


Figure 5. Current Gain — Bandwidth Product

Figure 6. Capacitance

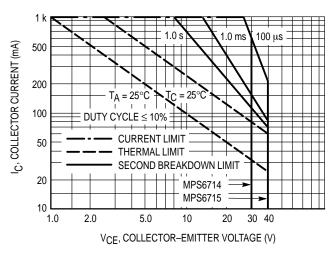
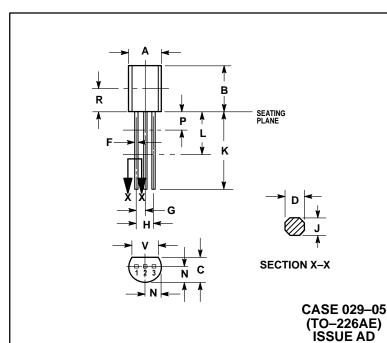


Figure 7. Active Region — Safe Operating Area

#### PACKAGE DIMENSIONS



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.

  4. DIMENSION F APPLIES BETWEEN P AND L.
- DIMENSIONS D AND J APPLY BETWEEN L AND K
  MIMIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.022	0.46	0.56
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.135		3.43	
V	0.135		3.43	

STYLE 1:

**EMITTER** 

BASE COLLECTOR

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